查询TA8804F供应商 捷多邦，专业PCB打样工厂，24小时加急出货

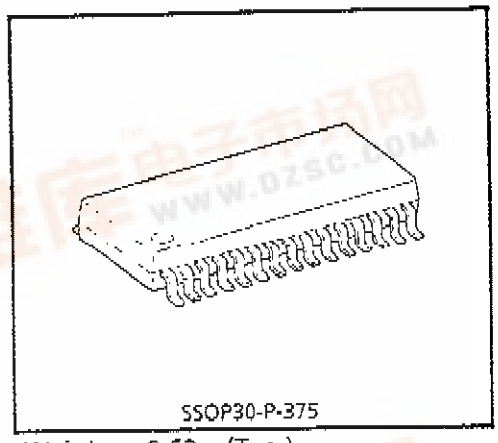
TOSHIBA INTEGRATED CIRCUIT TECHNICAL DATA

TA8804F

SILICON MONOLITHIC

FM DEMODULATION IC FOR BROADCASTING SATELLITE RECEIVER

The TA8804F combines the necessary function on a single monolithic integrated circuit to modulate FM signal of the 2nd IF of DBS.



SSOP30-P-375

Weight : 0.63g (Typ.)

FEATURES

- 5V Power Supply
- 2nd IF AGC Amp
- dB-Linear Signal Level Amp
- PLL FM Detector
- Keyed AFT

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The TOSHIBA products are intended for use in general commercial applications (office equipment, communication equipment, measuring

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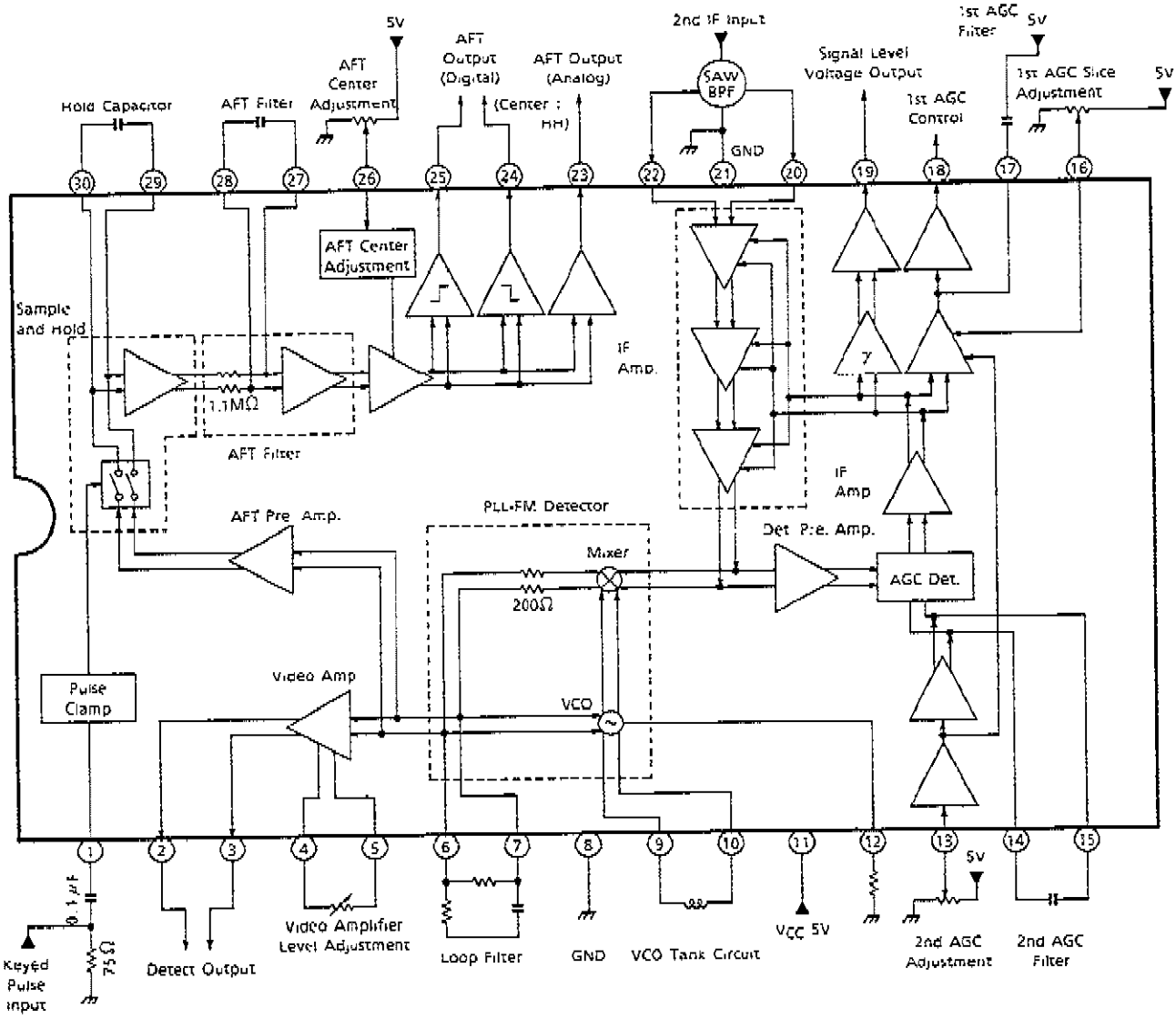
BLOCK DIAGRAM



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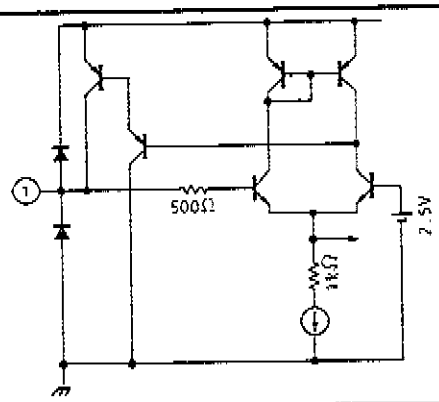
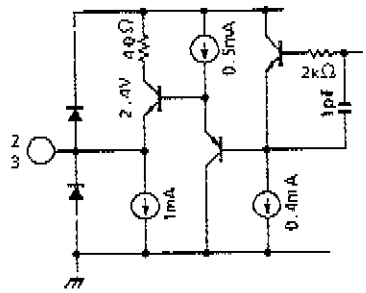
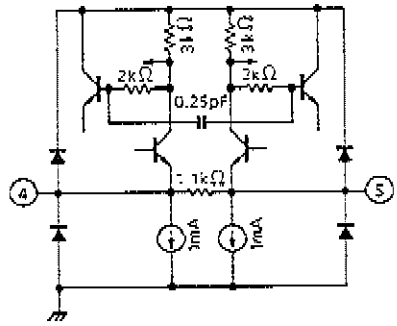
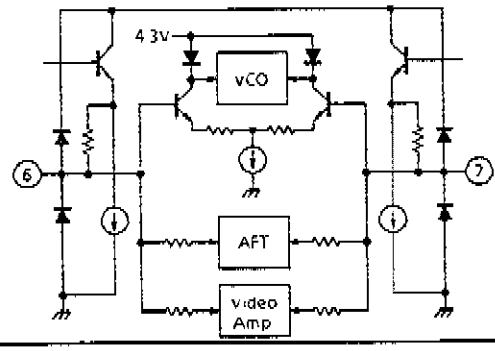
TERMINAL FUNCTION

PIN No.	PIN NAME	FUNCTION	INTERFACE CIRCUIT
1	Keyed Pulse Input	It clamps at the pulse peak and generates the reference level. The input impedance is 3kΩ. • If any keyed pulse input, Keyed pulse : low level sample state Keyed pulse : high level hold state • If no keyed pulse input, sample state at all time	
2 3	Detect Output	It outputs the detection output through a low-pass filter of 30MHz cut off frequency using an emitter follower.	
4 5	Video Amplifier Level Adjustment	It controls the level adjustment by varying the emitter resistance of a differential amplifier. If the resistance between pins 4 and 5 is reduced the output will be greater, however, since the output dynamic range is narrow the output level should be used in the range of lower than $0.7V_{p-p}$.	
6 7	Loop Filter	The output impedance is 200Ω. In the application circuit, $\omega \fallingdotseq 174MHz$ $\xi \fallingdotseq 0.81$	

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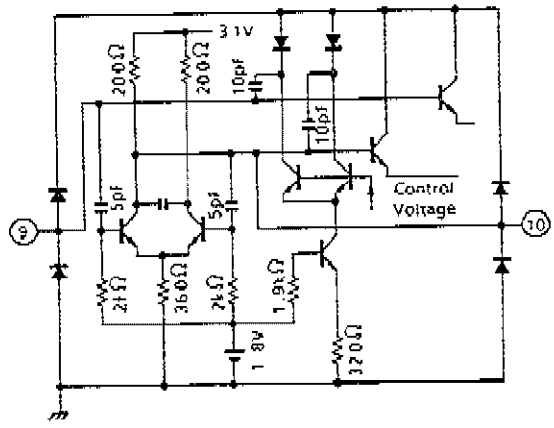
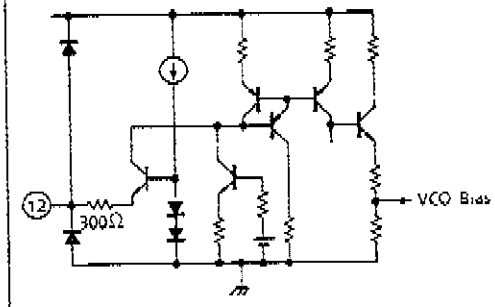
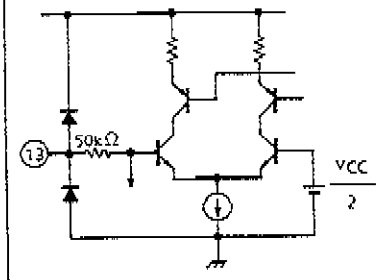
PIN No.	PIN NAME	FUNCTION	INTERFACE CIRCUIT
8	GND1	It is the GND of VCO circuit blocks that are VCO (pins 9, 10, 12), loop filter (pins 6, 7), video amplifier (pins 4, 5) AFT system (pins 1, 23, 24, 25, 26, 27, 28) and S/H (pins 29, 30).	—
9 10	VCO Coil	It is the VCO using variations in internal impedance of diode for control voltage from mixer. Use a UJ characteristic for the capacitor of the external tank circuit to correct the internal temperature drift.	
12	VCO Temperature Compensate Bias	The VCO bias is composed of a synthesis of bias in proportion to V_{BE} and V_T of transistor, and this terminal generates a bias proportioned to the V_{BE}. If the external resistance reduced, the VCO sensitivity will rise.	
13	2nd AGC Adjustment	It changes the input level for a AGC detector. It adjusts by adding the direct current offset to pins 14 and 15. The variation width of about 8dB can be added. Internal bias is 2.5V.	

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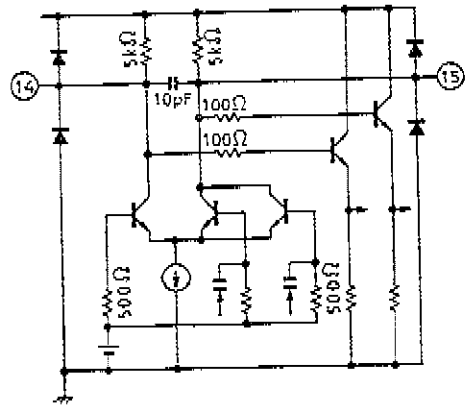
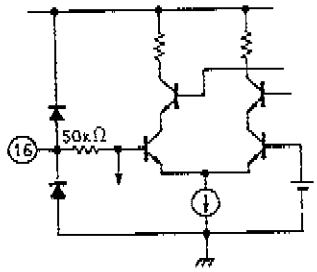
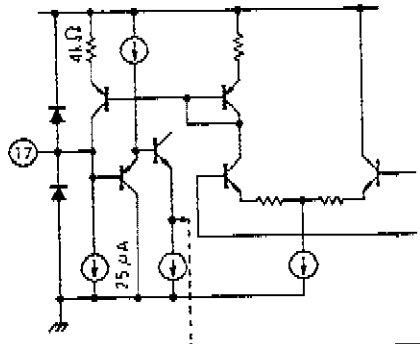
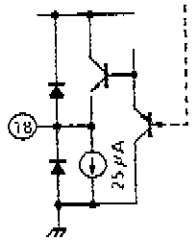
PIN No.	PIN NAME	FUNCTION	INTERFACE CIRCUIT
14 15	2nd AGC Filter	It generates the AGC voltage by filtering the 402.78MHz (479.5MHz) IF signal by means of an internal resistance and an external condenser. If applying the V_{CC} to pin 15, the AGC will be minimum gain and the VCO oscillates at free-running frequency.	
16	1st AGC Slice Adjustment	It sets the input level threshold for generating the control signal to lower gain from the IC to the 2nd converter of front stage when excessive input. Even if the 2nd AGC adjustment varies, the 1st AGC adjustment point hardly changes. The internal bias is 2.5V.	
17	1st AGC Filter	It outputs by comparating with the AGC and 1st AGC slice level adjustment voltages. This comparator is constructed by the active load type high gain amplifier and determines its response by a capacitor connected to this terminal.	
18	1st AGC Control	It outputs the control voltage using an emitter follower (active low level). The internal current sink has only 25μA.	

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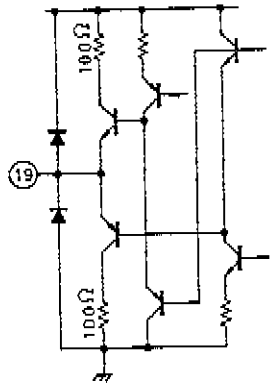
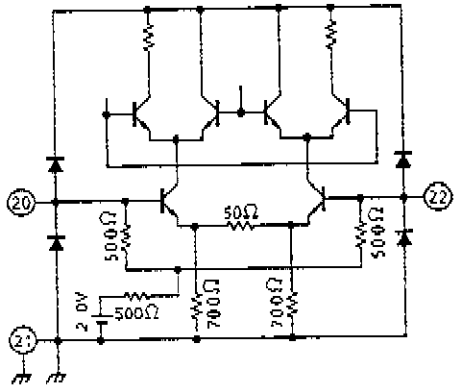
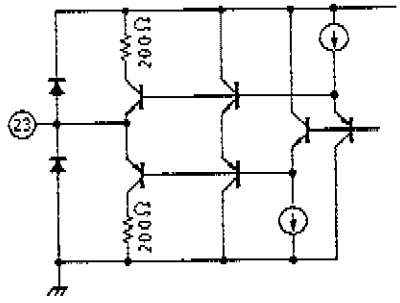
PIN No.	PIN NAME	FUNCTION	INTERFACE CIRCUIT
19	Signal Level Out	It outputs the AGC voltage by doing logarithm <-> linear conversion. In the TA8804F the level detection can be carried out even after the 1st AGC is effective and input is reduced using the 1st AGC output.	
20 22	2nd IF In	The IF amplifier constructed by the 3-step series connection of variable gm type gain control, of which the maximum gain is 47dB and minimum gain −8dB. In order to prevent a sneak of radio frequency all the circuits are balance-connected. Therefore, the differential combination is also desirable for the IC input. The internal bias is 2.0V and input impedance 1kΩ.	
23	AFT Output (Analog)	It outputs by integrating the detection output by means of pin 27 and 28 filters, doing center adjustment and multiplying about five times as much.	

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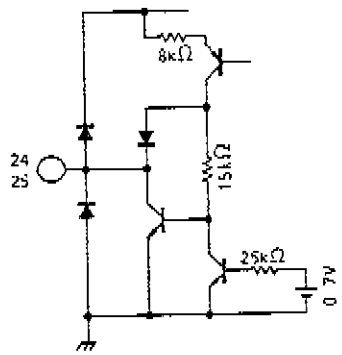
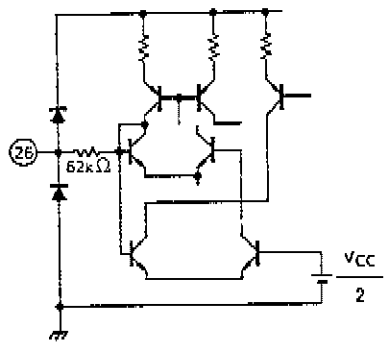
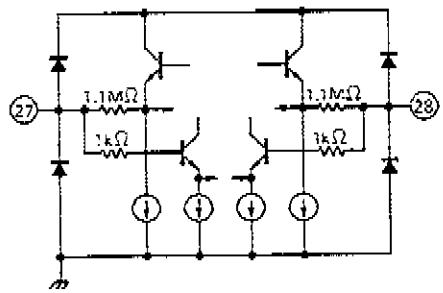
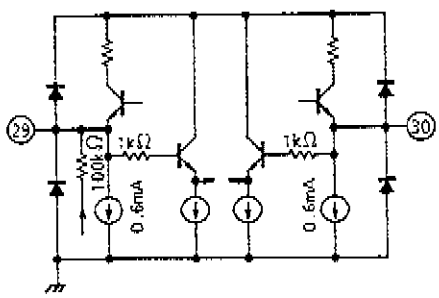
PIN No.	PIN NAME	FUNCTION	INTERFACE CIRCUIT
24 25	AFT Output (Digital)	It outputs by converting the analog AFT output to binary with a comparator. In the case of center detection, the each output will be high level. The width of dead gone is determined by the internal threshold and VCO sensitivity, that cannot be adjusted externally.	
26	AFT Center Adjustment	It moves the AFT center frequency in the width of 10MHz and absorbs the center gap caused by dispersion of each AFT circuit.	
27 28	AFT Filter	It constructs a filter whose cut off frequency is less than 1Hz (capacitor : 0.7Hz at 0.1μF) with an internal 1.1MΩ resistance and external condenser.	
29 30	Hold Capacitor	Sample and hold by charge / discharging the condenser using the switching signal regenerated by keyed pulse.	

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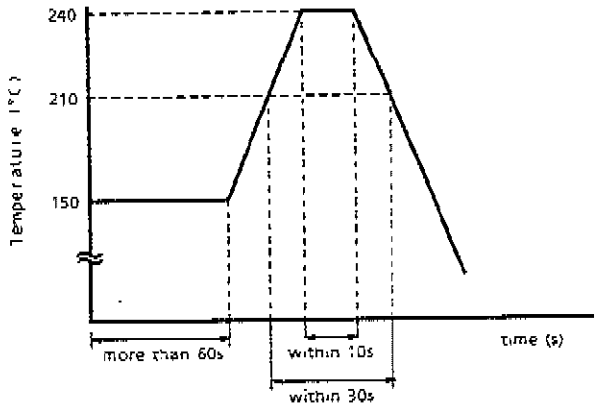
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	V_{CC} MAX	6.0	V
Power Dissipation	P_D MAX	1000	mW
Operation Temperature	T_{opr}	−20~75	°C
Storage Temperature	T_{stg}	−55~150	°C
Lead Temperature	—	260°C, 10s	

Recommended assembly method : Recommended temperature profile of reflow soldering of far and medium infrared rays



RECOMMENDED POWER SUPPLY VOLTAGE

PIN No.	PIN NAME	MIN.	TYP.	MAX.	UNIT
11	V_{CC}	4.5	5.0	5.5	V

ELECTRICAL CHARACTERISTICS

DC CHARACTERISTICS (Unless otherwise specified, V_{CC} = 5.0V, Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current		I_{CC}	1	—	55	80	105	mA
Terminal Voltage	Pin 1	V_1	1	—	2.0	2.5	3.0	V
	Pin 2	V_2		—	1.9	2.4	2.9	
	Pin 3	V_3		—	1.9	2.4	2.9	
	Pin 4	V_4		—	0.8	1.3	1.8	
	Pin 5	V_5		—	0.8	1.3	1.8	
	Pin 6	V_6		—	1.7	2.1	2.5	
	Pin 7	V_7		—	1.7	2.1	2.5	
	Pin 9	V_9		—	2.4	2.8	3.2	
	Pin 10	V_{10}		—	2.4	2.8	3.2	
	Pin 12	V_{12}		—	0.4	0.7	1.0	
	Pin 13	V_{13}		—	2.3	2.5	2.7	
	Pin 14	V_{14}		—	—	3.6	—	
	Pin 15	V_{15}		—	—	3.6	—	
	Pin 16	V_{16}		—	2.1	2.5	2.9	
	Pin 18	V_{18h}		Pin 17 : 1kΩ-GND	—	1.0	1.3	
		V_{18l}		Pin 17 : V_{CC}	3.9	4.3	4.7	
	Pin 20	V_{20}		—	1.5	2.0	2.5	
	Pin 22	V_{22}		—	1.5	2.0	2.5	
	Pin 27	V_{27}		—	—	2.3	2.8	
	Pin 28	V_{28}		—	—	2.3	2.8	
	Pin 29	V_{29}		—	1.8	2.3	2.8	
	Pin 30	V_{30}		—	1.8	2.3	2.8	
Pin 2, 3 Acceptable Output Current		I_2, I_3	1	—	−1.0	—	6.0	mA
1'st AGC Output Current		I_{18}	1	—	−0.02	—	6.0	mA

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AC CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
IF Input Frequency Range	f_{in}	—	—	350	400	550	MHz
IF Input Level Range	v_{in}	—	—	−60	—	−10	dBmW (50Ω)
1st AGC Shoulder Level Range	AGC_{MAX}	2	(Note 1)	—	−20	−10	dBmW (50Ω)
1st AGC Control Sensitivity	ΔAGC	2	(Note 2)	1.0	3.5	6.0	V/dB
Signal Level Sensitivity	ΔV/Δv	2	(Note 3)	10	35	60	mV/dB
VCO Conversion Sensitivity	β	2	Converting to output rate Pin 4, 5 : open / (Note 4)	—	110	130	MHz/V
VCO Temperature Drift	Δf_{Ta}	2	Ta = −10~65°C / (Note 5)	—	±1.0	±2.5	MHz
PLL Lock Range	f_L	2	(Note 6)	±25	±30	—	MHz
PLL Capture Range	fca	2	(Note 6)	±25	±30	—	MHz
Demodulation Output Level	V_{out}	2	$\Delta f = 10MHz_{p-p}$ / (Note 7)	0.15	0.26	0.40	V_{p-p}
Video Amplifier Variable Width	$V_{outS/5}$	2	Pin 4, 5 : short, 5kΩ / (Note 8)	10	14	—	dB
Demodulation Output Amplitude Frequency Characteristics 1	V_{outA1}	2	f = 0.2~4MHz / (Note 9)	—	—	±0.5	dB
Demodulation Output Amplitude Frequency Characteristics 2	V_{outA2}	2	f = 4~9MHz / (Note 9)	—	—	±2	dB
Group Delay Characteristics 1	τpd1	2	f = 0.2~4MHz / (Note 9)	—	—	±10	ns
Group Delay Characteristics 2	τpd2	2	f = 4~9MHz / (Note 9)	—	—	±40	ns
AFT Sensitivity	Δf/ΔV	2	(Note 12)	2.4	3.2	4.0	MHz/V
S/H Sample Speed	Δf_{spl}	2	Converting to input frequency rate / (Note 10)	0.1	0.2	—	MHz/μs
Keyed AFT Input Range	V_1	2	—	0.35	0.5	0.65	V_{p-p}
Keyed AFT Input Frequency	T_1	2	(Note 11)	8.0	16.7	50	ms
AFT Width of Dead Zone	V_{DEAD}	2	(Note 13)	250	340	400	kHz
Digital AFT Voltage Low Level	V_{20L}	2	(Note 13)	—	0.3	0.5	V
DG	DG	application circuit	APL 90% / (Note 14)	—	±2.0	±5.0	%

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DP	DP	application circuit	APL 90% / (Note 14)	—	±2.0	±5.0	°
Inter-Modulation 2	IM2	application circuit	2.15MHz beat level / (Note 15)	40	45	—	dB
Inter-Modulation 3	IM3	application circuit	1.43MHz beat level / (Note 15)	40	50	—	dB
Video Output S/N	S/N_{SAT}	application circuit	C/N = ∞	48	51	—	dB

MEASUREMENT CONDITION

(Note 1) 1st AGC Shoulder Level Range : AGC_{MAX}

F = 402.78MHz input level v_{in} = 0 to −40dBmW (50Ω) to pin 20. Measure v_{in} that pin 18 voltage is lower than 4V by opening pin 16 and raising v_{in}.

(Note 2) 1st AGC Control Sensitivity : ΔAGC

Input f = 402.78MHz v_{in} = 0~−40dBmW (50Ω) to pin 20. Calculate v_{in} that pin 18 voltage is 4V / 1V (as v_{in1}, v_{in2}), using the equation below.

$\Delta AGC = -3 / (v_{in1} - v_{in2})$ V/dB

(Note 3) Signal Level Sensitivity : ΔV/Δv

Measure each output voltage of pin 19 at v_{in} = −40, −60dBmW (50Ω)

$\Delta V / \Delta V = (V_{-60} - V_{-40}) / 20$ mV/dB

(Note 4) VCO Conversion Sensitivity : β

Input mainly f = 402.78MHz and sweep ±5MHz, v_{in} = −30dBmW (50Ω) to pin 20. Calculate $\beta = 10 / (Vdet_{+5} - Vdet_{-5})$ and multiply the gain portion (2.66) of video amplifier when outputting a direct current voltage to pin 3 at 407.78MHz, 397.78MHz as $Vdet_{+5}$ and $Vdet_{-5}$ each.

(Note 5) VCO Temperature Drift : Δf_{Ta}

Short pin 6 and 7, and connect pin 14 to GND.
Measure the VCO frequency at ambient temperature Ta = 25°C, −10°C +65°C and calculate how much changes from 25°C. (read out the VCO leakage output by spectrum analyzer.)

(Note 6) PLL Lock Range : f_L, Capture Range : fca

Measure the range that synchronizes with VCO by putting pin 20 input frequency away from the free-running frequency.

(Note 7) Demodulation Output Level : V_{out}

Input pin 20 f = 402.78MHz, f_m = 100kHz, Δf = 10MHz$_{p-p}$, v_{in} = −30dBmW (50Ω)
Open pin 4 and 5 and measure the output level of pin 3.

(Note 8) Video Amplifier Variable Width : V_{out5}, V_{out5}

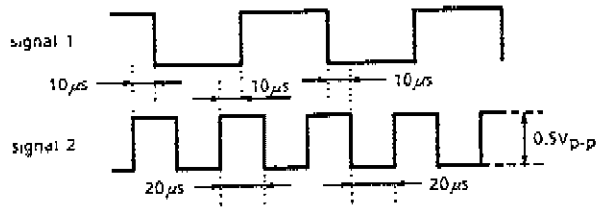
Input pin 20 f = 402.78MHz, f_m = 100kHz, Δf = 10MHz$_{p-p}$, v_{in} = −30dBmW (50Ω)
Measure the variation of video output by shorting between pin 4 and 5 and connecting a 5kΩ resistance.

(Note 9) Demodulation Output level Width, Group Delay Characteristics : V_{outA}, τpd

Input pin 20 f = 402.78MHz, f_m = 100kHz, 60Hz to 4MHz to 9MHz, Δf = 5MHz$_{p-p}$, v_{in} = −30dBmW (50Ω)
Compare to the value at 100kHz by opening pin 4 and 5, and measuring the output level and group delay of pin 3.

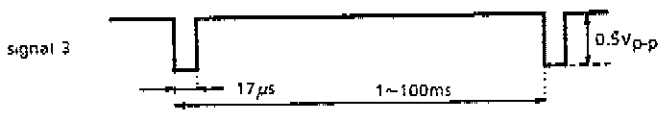
(Note 10) S/H Sample Speed : Δf_{spl}

Input the signal 1 below for a modulation signal. Input the signal 2 below to pin 1. Observe the differential voltage waveform between pin 29 and 30, and measure the slew rate in the sampling period.



(Note 11) Keyed Pulse Allowable Period : T_1

Input the signal below to pin 1 and open pin 27 and 28. Observe the pin 23 output and change f so as to be 2.5V voltage.



Measure the frequency range in which a 2kHz sine wave does not output to pin 23, by changing the signal 3 period.
If the sample-hold circuit malfunctions, the 2kHz sine wave will be outputted from pin 23.

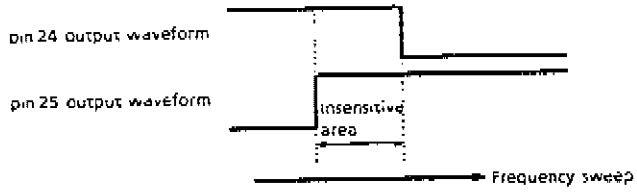
(Note 12) AFT Sensitivity : $\Delta f / \Delta V_{23}$

Input pin 20 f = 402.78MHz ± 1MHz, v_{in} = −30dBmW (50Ω)
Adjust f so that pin 23 output will be 2.5V. By moving f up. and down, calculate each frequency as f_H, f_L when pin 23 voltage varies 0.5V using the following equation.

$\Delta f / \Delta V_{23} = f_H - f_L$ (MHz / V)

(Note 13) AFT Digital Output Width of Blind Sector : f_{DEAD}

Input pin 20 f = 402.78MHz ± 5MHz, v_{in} = −30dBmW (50Ω)
Measure the input frequency range in which both pin 24 and 25 become high level, by sweeping f.



(Note 14) DG, DP

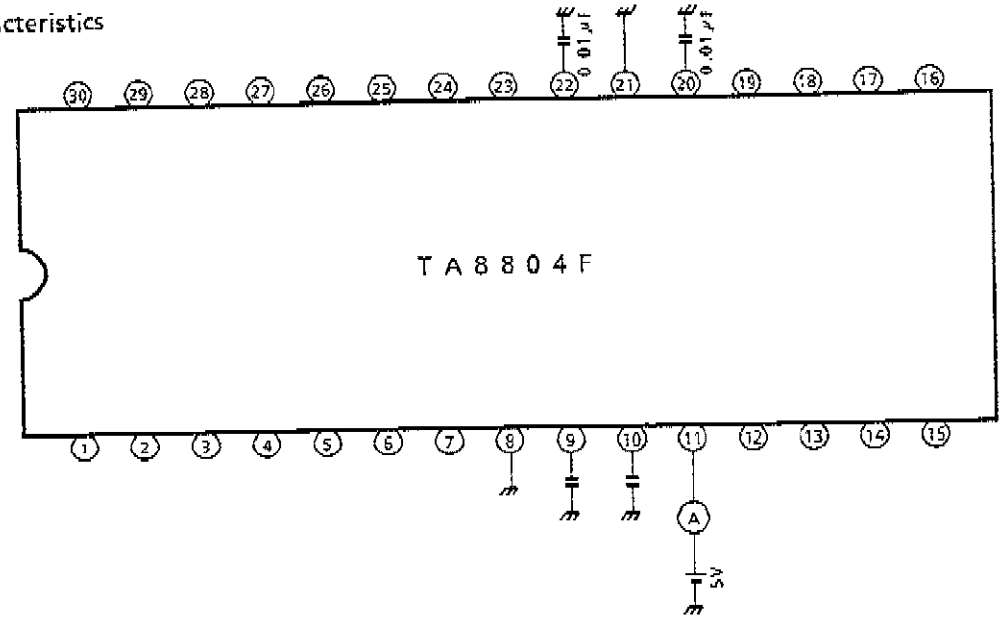
Input pin 20 f = 402.78MHz ± 5MHz, v_{in} = −30dBmW (50Ω), $\Delta f = 17MHz_{p-p}$, Gray level video signal (APL : 10~90%)··· Pre-emphasis-on

(Note 15) IM2, IM3

Input pin 20 f = 402.78MHz ± 5MHz, v_{in} = −30dBmW (50Ω), $\Delta f = 17MHz_{p-p}$, Color subcarrier (3.579MHz), Sound subcarrier (5.7272MHz) ···
Observe the frequency component outputting to the screen output pin (pin 3) through the video gate of a video noise meter by spectrum analyzer, and measure the level difference between 3.579MHz component and 2.15MHz, 1.43MHz components.

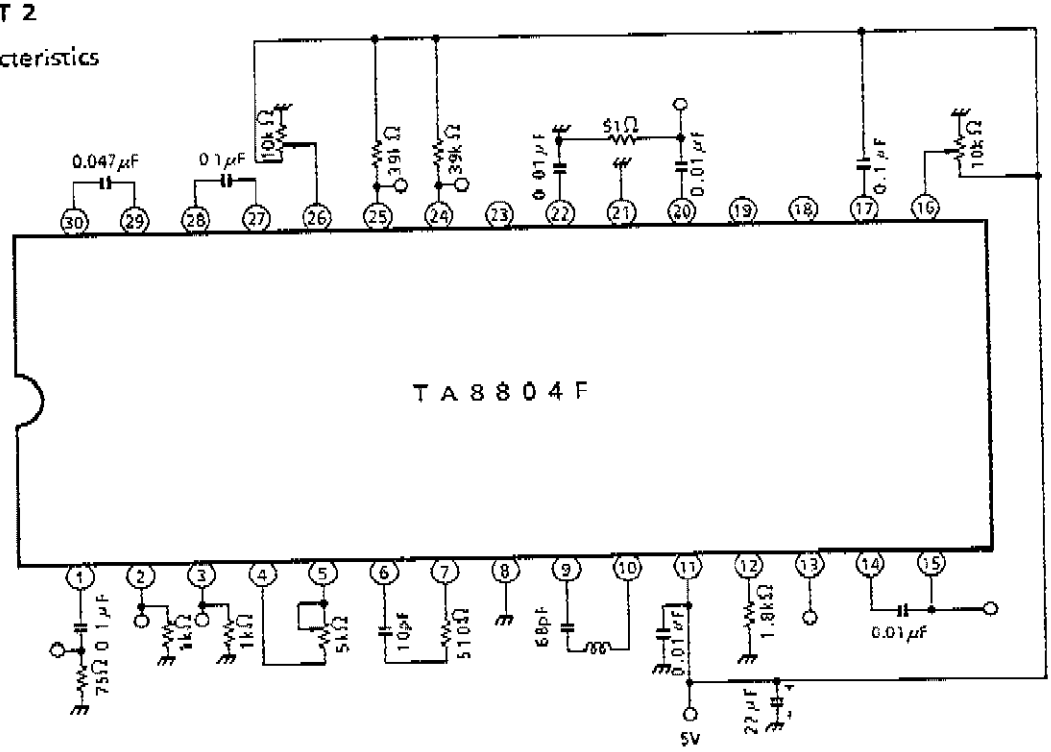
TEST CIRCUIT 1

DC characteristics



TEST CIRCUIT 2

AC characteristics



INTEGRATED CIRCUIT

TOSHIBA

TECHNICAL DATA

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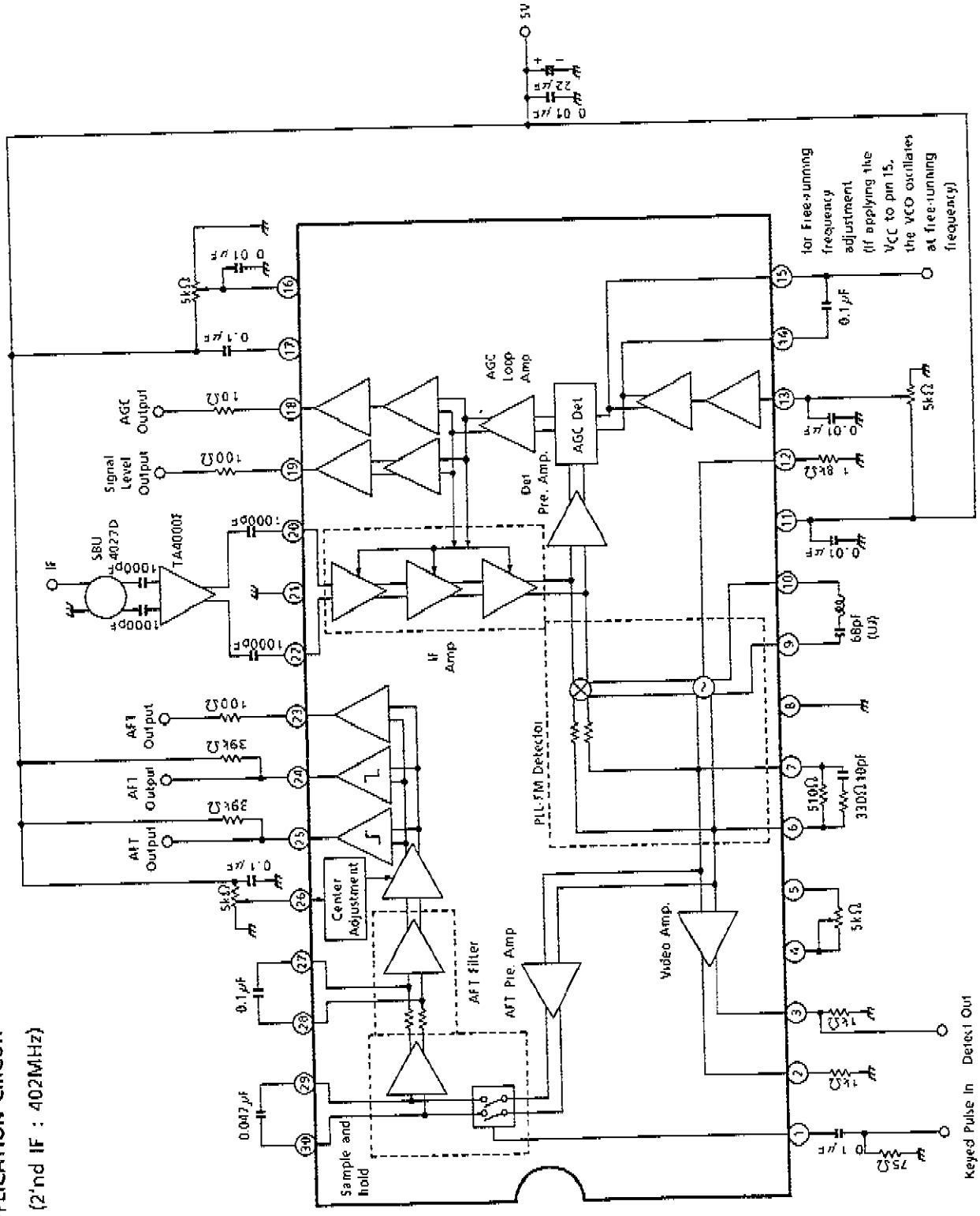
APPLICATION CIRCUIT

(2'nd IF : 402MHz)



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INTEGRATED CIRCUIT

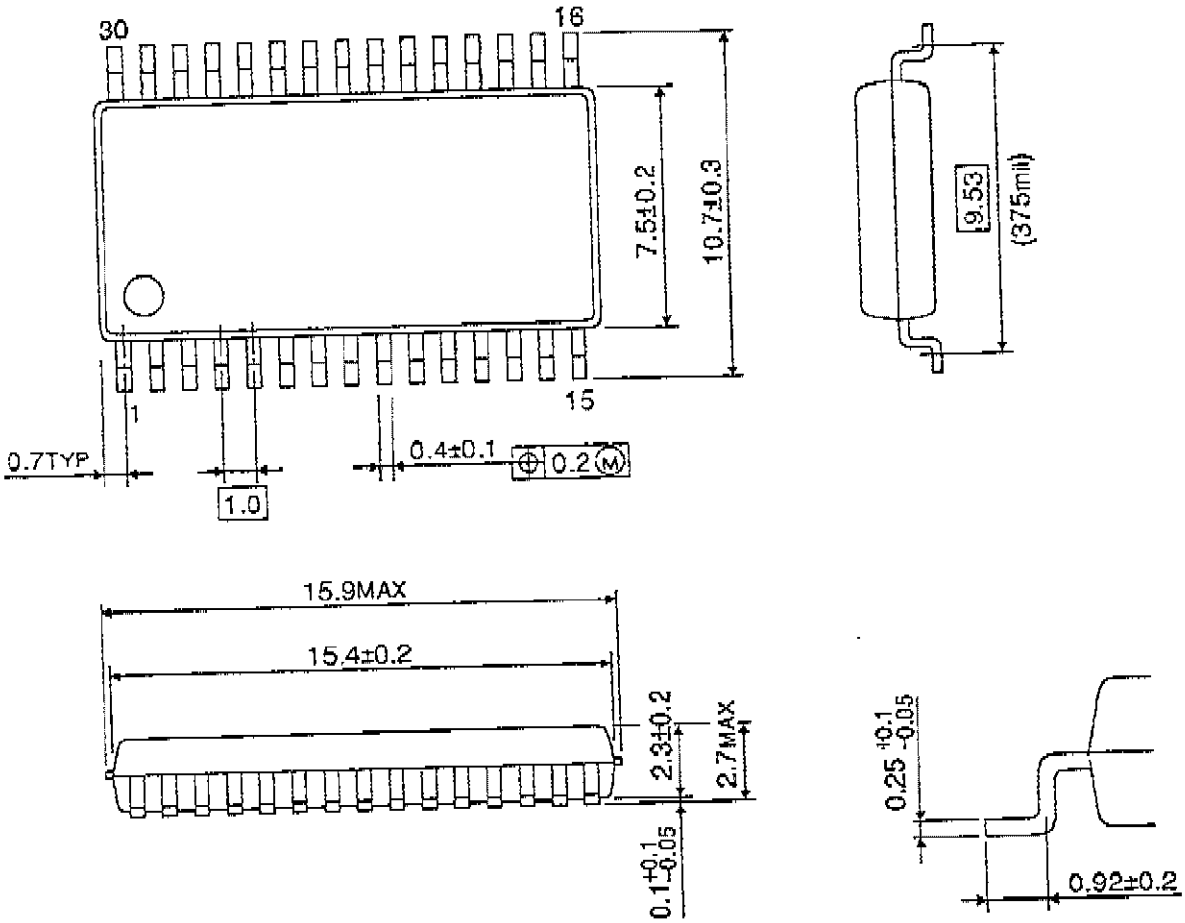
TOSHIBA TECHNICAL DATA

TA8804F

OUTLINE DRAWING

SSOP30-P-375

Unit : mm



Weight : 0.63g (Typ.)

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